

MSD42WT1, MSD42T1

Preferred Device

NPN Silicon General Purpose High Voltage Transistors

This NPN Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 and SC-59 packages which are designed for low power surface mount applications.

Features

- Pb-Free Package is Available

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{(BR)CBO}$	300	Vdc
Collector-Emitter Voltage	$V_{(BR)CEO}$	300	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	6.0	Vdc
Collector Current – Continuous	I_C	150	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P_D	150	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-55 \sim +150$	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

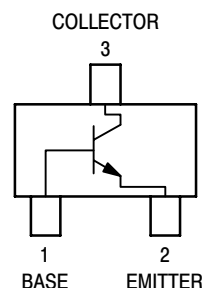
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ($I_C = 1.0 \text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	300	–	Vdc
Collector-Base Breakdown Voltage ($I_C = 100 \mu\text{Adc}$, $I_E = 0$)	$V_{(BR)CBO}$	300	–	Vdc
Emitter-Base Breakdown Voltage ($I_E = 100 \mu\text{Adc}$, $I_C = 0$)	$V_{(BR)EBO}$	6.0	–	Vdc
Collector-Base Cutoff Current ($V_{CB} = 200 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	–	0.1	μA
Emitter-Base Cutoff Current ($V_{EB} = 6.0 \text{ Vdc}$, $I_B = 0$)	I_{EBO}	–	0.1	μA
DC Current Gain (Note 2) ($V_{CE} = 10 \text{ Vdc}$, $I_C = 1.0 \text{ mAdc}$) ($V_{CE} = 10 \text{ Vdc}$, $I_C = 30 \text{ mAdc}$)	h_{FE1} h_{FE2}	25 40	– –	–
Collector-Emitter Saturation Voltage (Note 2) ($I_C = 20 \text{ mAdc}$, $I_B = 2.0 \text{ mAdc}$)	$V_{CE(sat)}$	–	0.5	Vdc

- Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.
- Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, D.C. $\leq 2\%$.



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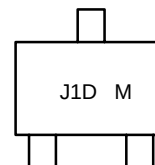
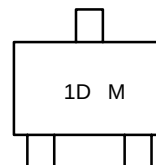


SC-70 (SOT-323)
CASE 419
(SCALE 2:1)



SC-59
CASE 318D
(SCALE 2:1)

MARKING DIAGRAMS



1D = Device Marking Code
M = Date Code

ORDERING INFORMATION

Device	Package	Shipping†
MSD42WT1	SC-70/SOT-323	3000/Tape & Reel
MSD42WT1G	SC-70/SOT-323	3000/Tape & Reel
MSD42T1	SC-59	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

MSD42WT1, MSD42T1

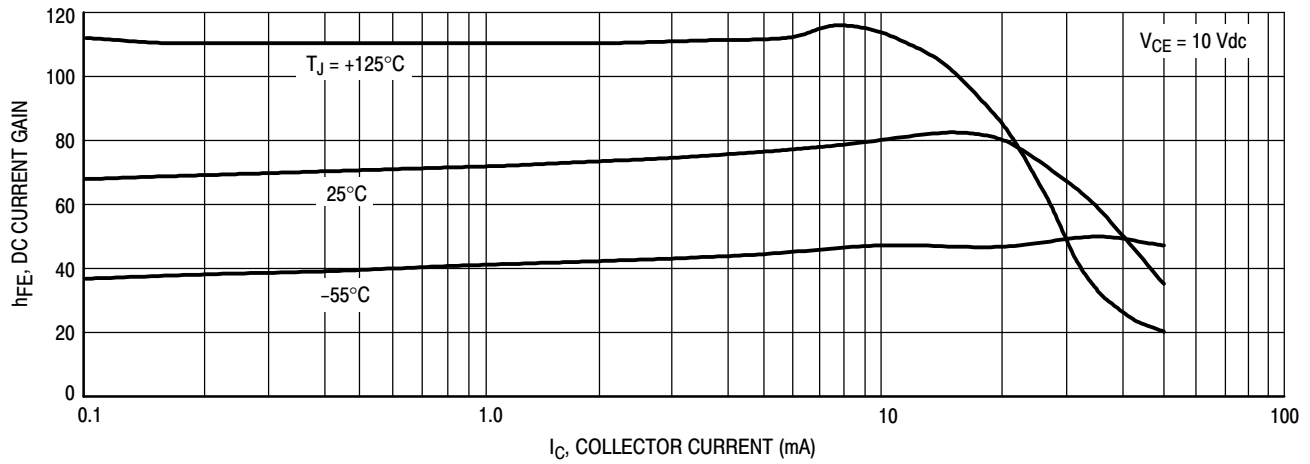


Figure 1. DC Current Gain

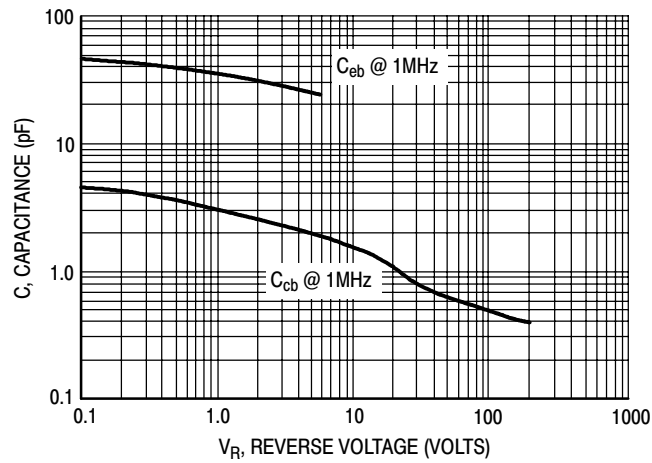


Figure 2. Capacitance

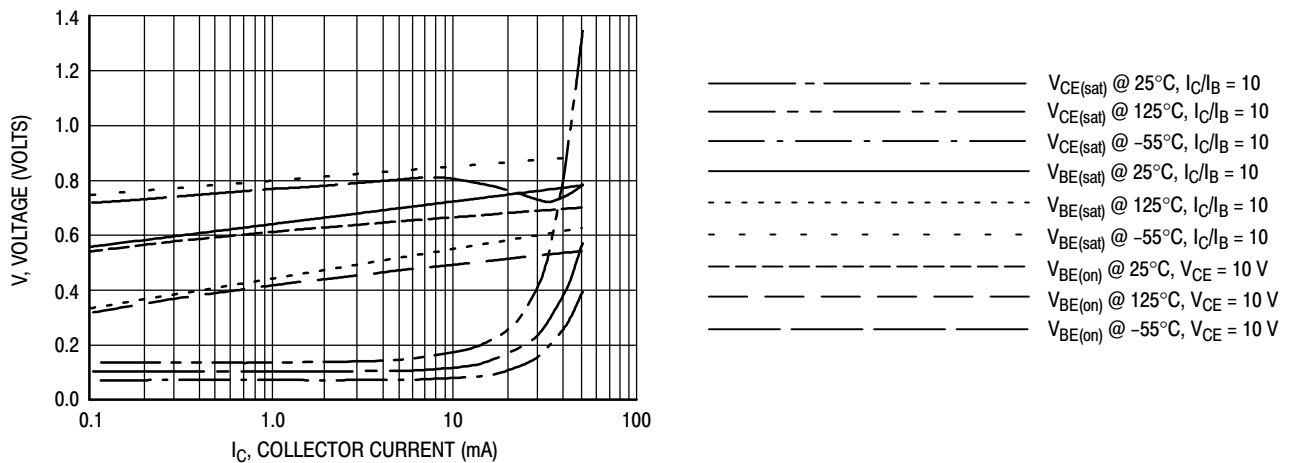
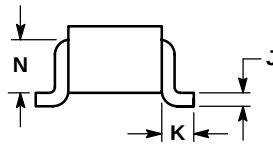
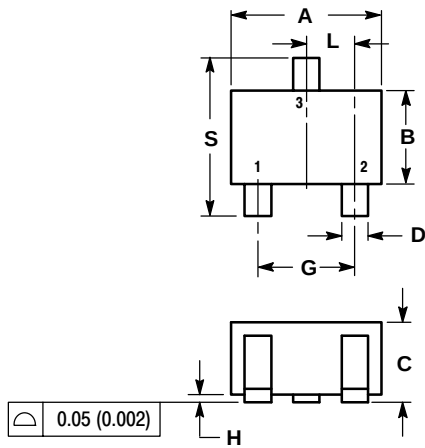


Figure 3. "ON" Voltages

MSD42WT1, MSD42T1

PACKAGE DIMENSIONS

SC-70 (SOT-323)
CASE 419-04
ISSUE L



NOTES:

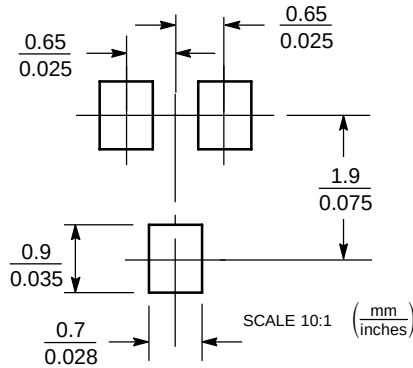
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40

STYLE 3:

- PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



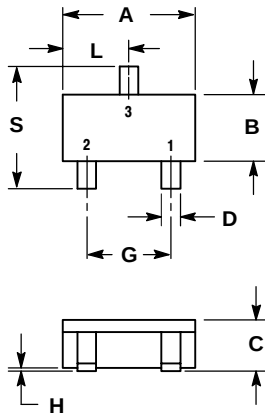
SC-70/SOT-323

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MSD42WT1, MSD42T1

PACKAGE DIMENSIONS

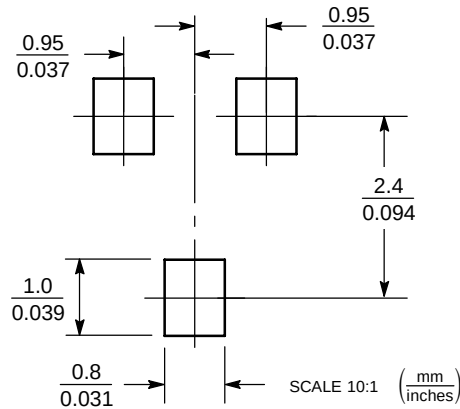
SC-59
CASE 318D-04
ISSUE F



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.70	3.10	0.1063	0.1220
B	1.30	1.70	0.0512	0.0669
C	1.00	1.30	0.0394	0.0511
D	0.35	0.50	0.0138	0.0196
G	1.70	2.10	0.0670	0.0826
H	0.013	0.100	0.0005	0.0040
J	0.09	0.18	0.0034	0.0070
K	0.20	0.60	0.0079	0.0236
L	1.25	1.65	0.0493	0.0649
S	2.50	3.00	0.0985	0.1181

SOLDERING FOOTPRINT*



SC-59

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

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